

### **DS36950**

### **Quad Differential Bus Transceiver**

### **General Description**

The DS36950 is a low power, space-saving quad EIA-485 differential bus transceiver especially suited for high speed, parallel, multipoint, computer I/O bus applications. A compact 20-pin surface mount PLCC package provides high transceiver integration and a very small PC board footprint.

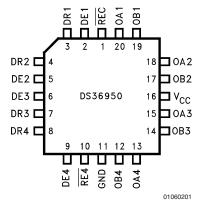
Timing uncertainty across an interface using multiple devices, a typical problem in a parallel interface, is specified—minimum and maximum propagation delay times are guaranteed.

Six devices can implement a complete IPI master or slave interface. Three transceivers in a package are pinned out for connection to a parallel databus. The fourth transceiver, with the flexibility provided by its individual enables, can serve as a control bus transceiver.

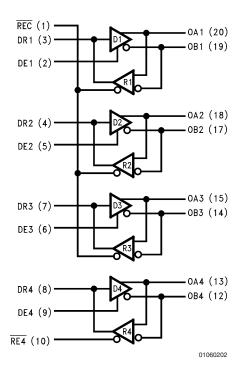
### **Features**

- Pinout for IPI interface
- Compact 20-pin PLCC package
- Meets EIA-485 standard for multipoint bus transmission
- Greater than 60 mA source/sink
- Thermal Shutdown Protection

### **Pinout and Logic Diagram**



Order Number DS36950 See NS Package Number V20A



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### **Absolute Maximum Ratings** (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Driver Output Voltage/Receiver

Input Voltage -10V to +15V

Receiver Output Voltage 5.5V

Continuous Power Dissipation @

25°C

V Package 1.73W

Derate V Package 13.9 mW/°C above 25°C

Storage Temp. Range  $-65^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$  Lead Temp. (Soldering 4 Sec.)  $260^{\circ}\text{C}$ 

# Recommended Operating Conditions

Supply Voltage,  $V_{CC}$  4.75V to 5.25V Bus Voltage -7V to +12V Operating Free Air Temp. ( $T_A$ ) 0°C to +70°C

### **Electrical Characteristics** (Note 2)

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур	Max	Units
DRIVER CI	HARACTERISTICS					
$V_{ODL}$	Differential Driver Output	$I_L = 60 \text{ mA}$	1.5	1.9		V
	Voltage (Full Load)	$V_{CM} = 0V$				
V <sub>OD</sub>	Differential Driver Output	$R_{L} = 100\Omega \text{ (EIA-422)}$	2.0	3.5		V
	Voltage (Termination Load)	$R_L = 54\Omega \text{ (EIA-485)}$	1.5	3.2		V
ΔIV <sub>OD</sub> I	Change in Magnitude of Driver	$R_L = 54\Omega$ or $100\Omega$				
	Differential Output Voltage for	(Note 4) (Figure 1)			0.2	V
	Complementary Output States	(EIA-485)				
V <sub>OC</sub>	Driver Common Mode Output	$R_L = 54\Omega$			3.0	V
	Voltage (Note 5)	(Figure 1) (EIA-485)				
$\Delta IV_{OC}I$	Change in Magnitude of Common	(Note 4) (Figure 1)			0.2	V
	Mode Output Voltage	(EIA-485)				
V <sub>OH</sub>	Output Voltage HIGH	$I_{OH} = -55 \text{ mA}$	2.7	3.2		V
V <sub>OL</sub>	Output Voltage LOW	I <sub>OL</sub> = 55 mA		1.4	1.7	V
V <sub>IH</sub>	Input Voltage HIGH		2.0			V
V <sub>IL</sub>	Input Voltage LOW				0.8	V
V <sub>CL</sub>	Input Clamp Voltage	I = -18 mA			-1.5	V
I <sub>IH</sub>	Input High Current	V <sub>I</sub> = 2.4V (Note 3)			20	μΑ
I <sub>IL</sub>	Input Low Current	V <sub>I</sub> = 0.4V (Note 3)			-20	μΑ
I <sub>osc</sub>	Driver Short-Circuit	$V_O = -7V$ (EIA-4	85)	-130	-250	mA
	Output Current	$V_O = 0V$ (EIA-4	22)	-90	-150	mA
	(Note 9)	$V_O = +12V$ (EIA-4	85)	130	250	mA
RECEIVER	CHARACTERISTICS				'	
I <sub>OSR</sub>	Short Circuit Output Current	V <sub>O</sub> = 0V (Note 9)	-15	-28	-75	mA
l <sub>oz</sub>	TRI-STATE® Output Current	V <sub>O</sub> = 0.4V to 2.4V			20	μΑ
V <sub>OH</sub>	Output Voltage High	$V_{ID} = 0.20V, I_{OH} = -0.4 \text{ mA}$	2.4	3.0		V
V <sub>OL</sub>	Output Voltage Low	$V_{ID} = -0.20V, I_{OL} = 4 \text{ mA}$		0.35	0.5	V
V <sub>TH</sub>	Differential Input High	$V_{\rm O} = V_{\rm OH}, I_{\rm O} = -0.4 \text{ mA}$		0.03	0.20	V
	Threshold Voltage	(EIA-422/485)				
$V_{TL}$	Differential Input Low	$V_{O} = V_{OL}, I_{O} = 4.0 \text{ mA}$	-0.20	-0.03		V
	Threshold Voltage (Note 6)	(EIA-422/485)				
V <sub>HST</sub>	Hysteresis (Note 7)	V <sub>CM</sub> = 0V	35	60		mV
	ND RECEIVER CHARACTERISTICS					
V <sub>IH</sub>	Enable Input Voltage High		2.0			V
V <sub>IL</sub>	Enable Input Voltage Low				0.8	V

### Electrical Characteristics (Note 2) (Continued)

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified

Symbol	Parameter	Conditions		Min	Тур	Max	Units		
DRIVER AND RECEIVER CHARACTERISTICS									
V <sub>CL</sub>	Enable Input Clamp Voltage	I = -18 mA				-1.5	V		
I <sub>IN</sub>	Line Input Current	Other Input = 0V	V <sub>I</sub> = +12V		0.5	1	mA		
	(Note 8)		$V_1 = -7V$		-0.45	-0.8	mA		
I <sub>IH</sub>	Enable Input Current High	V <sub>OH</sub> = 2.4V	RE4 or DE			20	μA		
			REC			60	μA		
I <sub>IL</sub>	Enable Input Current Low	V <sub>OL</sub> = 0.4V	RE4 or DE			-20	μΑ		
			REC			-60	μA		
Icc	Supply Current (Note 10)	No Load, Outputs Enabled			75	90	mA		
I <sub>ccz</sub>	Supply Current (Note 10)	No Load, Outputs Disabled			50	70	mA		

### **Switching Characteristics**

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified

Symbol	Conditions		Min	Тур	Max	Units
DRIVER SIN	IGLE-ENDED CHARACTERISTICS					
t <sub>PZH</sub>	$R_L = 110\Omega \ (Figure \ 4)$			35	40	ns
t <sub>PZL</sub>	$R_L = 110\Omega$ (Figure 5)			25	40	ns
t <sub>PHZ</sub>	$R_L = 110\Omega$ (Figure 4)			15	25	ns
t <sub>PLZ</sub>	$R_L = 110\Omega$ (Figure 5)			35	40	ns
DRIVER DIF	FERENTIAL CHARACTERISTICS		•		,	
t <sub>R</sub> , t <sub>F</sub>	Rise & Fall Time	$R_L = 54\Omega$		13	16	ns
t <sub>PLHD</sub>	Differential Propagation	$C_L = 50 \text{ pF}$	9	15	19	ns
t <sub>PHLD</sub>	Delays (Note 15)	C <sub>D</sub> = 15 pF	9	15	19	ns
t <sub>SKD</sub>	It <sub>PLHD</sub> – t <sub>PHLD</sub> I Differential Skew	(Figures 3, 8)		3	6	ns
RECEIVER	CHARACTERISTICS	•	•			
t <sub>PLHD</sub>	Differential Propagation Delays		9	14	19	ns
t <sub>PHLD</sub>	$C_L = 15 \text{ pF}, V_{CM} = 1.5V (Figure 6)$		9	14	19	ns
t <sub>SKD</sub>	It <sub>PLHD</sub> – t <sub>PHLD</sub> I Differential Receiver Skew			1	3	ns
t <sub>zH</sub>	Output Enable Time to High Level			15	22	ns
t <sub>ZL</sub>	Output Enable Time to Low Level	$C_L = 15 pF$		20	30	ns
t <sub>HZ</sub>	Output Disable Time from High Level	(Figure 7)		10	17	ns
t <sub>LZ</sub>	Output Disable Time from Low Level	1		17	25	ns

**Note 1:** "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Electrical Characteristics" specify conditions for device operation.

Note 2: Current into device pins is define as positive. Current out of device pins is defined as negative. All voltages are referenced to ground unless otherwise specified.

- Note 3:  $I_{IH}$  and  $I_{IL}$  includes driver input current and receiver TRI-STATE leakage current.
- Note 4:  $\Delta IV_{OD}I$  and  $\Delta IV_{OC}I$  are changes in magnitude of  $V_{OD}$  and  $V_{OC}$ , respectively, that occur when the input changes state.
- Note 5: In EIA Standards EIA-422 and EIA-485,  $V_{OC}$ , which is the average of the two output voltages with respect to ground, is called output offset voltage,  $V_{OS}$ .
- Note 6: Threshold parameter limits specified as an algebraic value rather than by magnitude.
- Note 7: Hysteresis defined as  $V_{HST} = V_{TH} V_{TL}$ .
- Note 8:  $I_{IN}$  includes the receiver input current and driver TRI-STATE leakage current.
- Note 9: Short one output at a time.
- Note 10: Total package supply current.
- Note 11: All typicals are given for  $V_{CC}=5.0V$  and  $T_{A}=25^{\circ}C.$

## **Parameter Measurement Information**

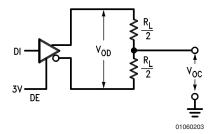


FIGURE 1. Driver  $\rm V_{\rm OD}$  and  $\rm V_{\rm OC}$ 

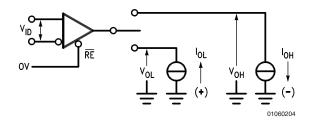
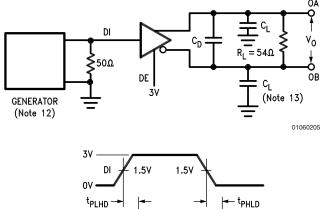
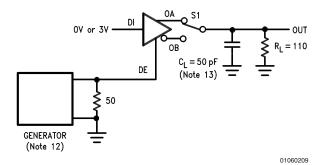


FIGURE 2. Receiver  $\rm V_{OH}$  and  $\rm V_{OL}$ 



OV - 1.5V 1.5V 1.5V + t<sub>PLHD</sub> + t<sub>PHLD</sub> + t<sub>PHLD</sub> + t<sub>P</sub> +

FIGURE 3. Driver Differential Propagation Delay and Transition Timing



S1 to OA for DI = 3VS1 to OB for DI = 0V

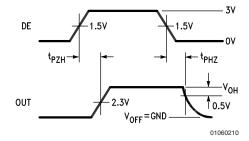
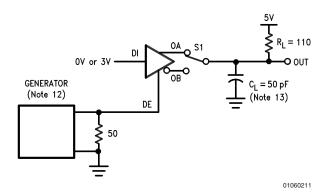


FIGURE 4. Driver Enable and Disable Timing ( $t_{\rm PZH},\,t_{\rm PHZ}$ )



S1 to OA for DI = 0VS1 to OB for DI = 3V

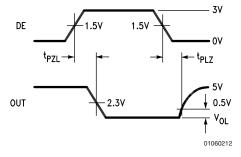


FIGURE 5. Driver Enable and Disable Timing ( $t_{PZL},\,t_{PLZ}$ )

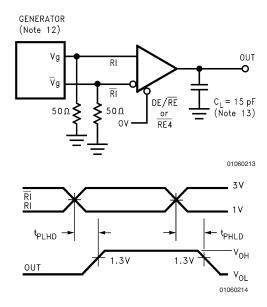
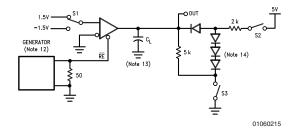
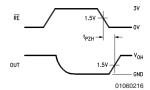
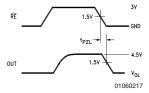


FIGURE 6. Receiver Differential Propagation Delay Timing

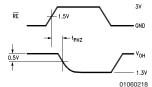




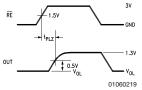
S1 1.5V S2 OPEN S3 CLOSED



S1 -1.5V S2 CLOSED S3 OPEN

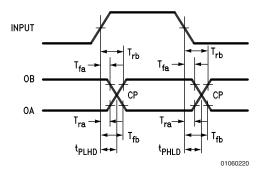


S1 1.5V S2 CLOSED S3 CLOSED



S1 -1.5V S2 CLOSED S3 CLOSED

FIGURE 7. Receiver Enable and Disable Timing



TCP = Crossing Point

Tra, Trb, Tfa, and Tfb are propagation delay measurements to the 20% and 80% levels.

$$\mathsf{TCP} = \frac{(\mathsf{Tfb} \times \mathsf{Trb}) - (\mathsf{Tra} \times \mathsf{Tfa})}{\mathsf{Trb} - \mathsf{Tra} - \mathsf{Tfa} + \mathsf{Tfb}}$$

#### FIGURE 8. Propagation Delay Timing for Calculation of Driver Differential Propagation Delays

Note 12: The input pulse is supplied by a generator having the following characteristics:

f = 1.0 MHz, 50% Duty Cycle,  $t_f$  and  $t_r \le 6.0$  ns,  $Z_O = 50\Omega$ 

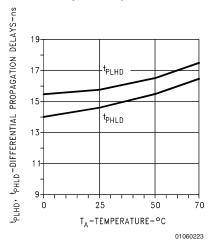
Note 13: C<sub>L</sub> includes probe and stray capacitance.

Note 14: Diodes are 1N916 or equivalent.

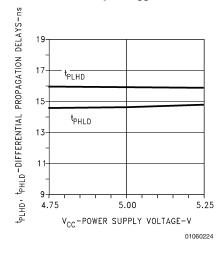
**Note 15:** Differential propagation delays are calculated from single-ended propagation delays measured from driver input to the 20% and 80% levels on the driver outputs (See *Figure 8*).

### **Typical Performance Characteristics**

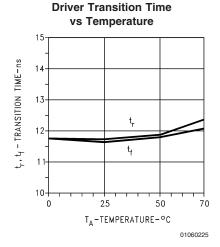
## Driver Differential Propagation Delay vs Temperature

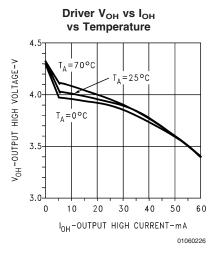


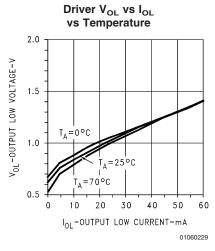
## Driver Differential Propagation Delay vs V<sub>CC</sub>

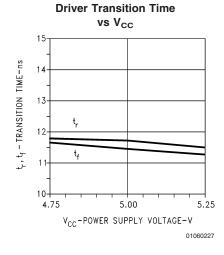


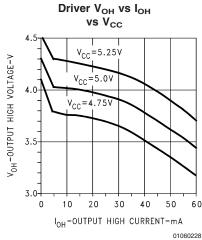
## **Typical Performance Characteristics** (Continued)

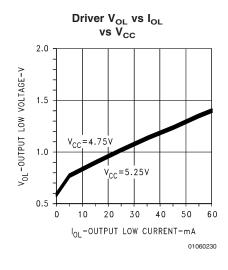




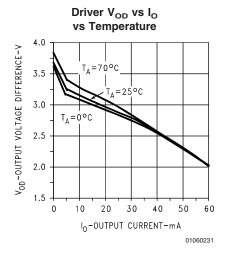




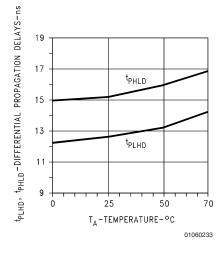




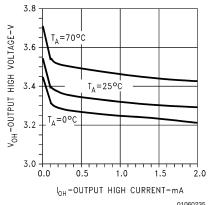
## **Typical Performance Characteristics** (Continued)

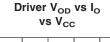


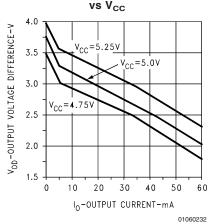
### **Receiver Differential Propagation Delay** vs Temperature



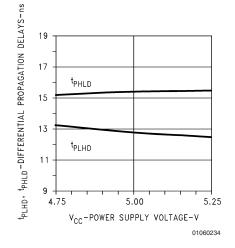
### Receiver $V_{\rm OH}$ vs $I_{\rm OH}$ vs Temperature



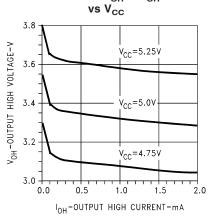




### **Receiver Differential Propagation** Delay vs V<sub>CC</sub>

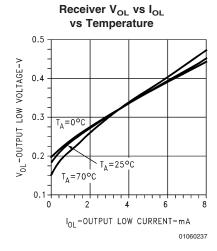


Receiver  $V_{\rm OH}$  vs  $I_{\rm OH}$ 

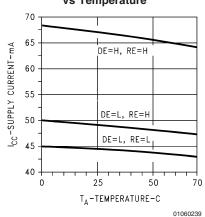


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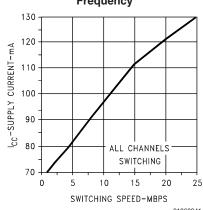
## **Typical Performance Characteristics** (Continued)



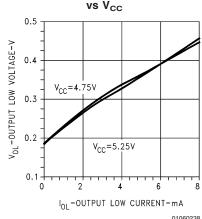




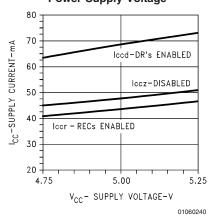
## Driver I<sub>CC</sub> vs Switching Frequency



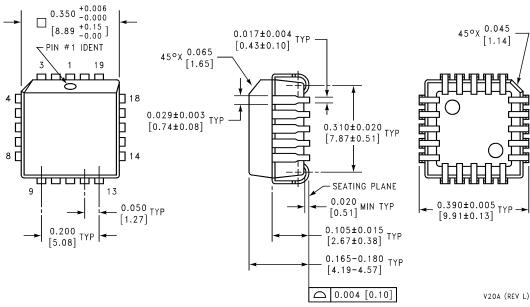
# Receiver $V_{\rm OL}$ vs $I_{\rm OL}$ vs $V_{\rm CC}$



### Power Supply Current vs Power Supply Voltage



### Physical Dimensions inches (millimeters) unless otherwise noted



Order Number DS36950 NS Package Number V20A

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